



IXFX210N17T Information

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For Reference Only

Part Number IXFX210N17T

Manufacturer IXYS

Category Discrete Semiconductor Products

Transistors - FETs, MOSFETs - Single

Description MOSFET N-CH 170V 210A PLUS247

Package TO-247-3

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









IXFX210N17T Specifications

Manufacturer Part Number	IXFX210N17T
Manufacturer	IXYS
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-247-3
Series	GigaMOS?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	170V
Current - Continuous Drain (Id) @ 25°C	210A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	5V @ 4mA
Gate Charge (Qg) (Max) @ Vgs	285nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	18800pF @ 25V
Vgs (Max)	±20V
FET Feature	-
Power Dissipation (Max)	1150W (Tc)
Rds On (Max) @ Id, Vgs	7.5 mOhm @ 60A, 10V
Operating Temperature	-55°C ~ 175°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	PLUS247?-3
Package / Case	TO-247-3
	Report errors?

IXFX210N17T Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

IXFX210N17T Payment Methods



















IXFX210N17T Shipping Methods













If you have any question about IXFX210N17T, please do not hesitate to contact us!

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